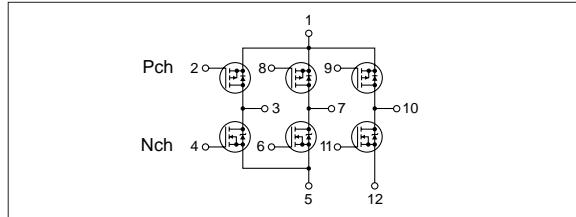
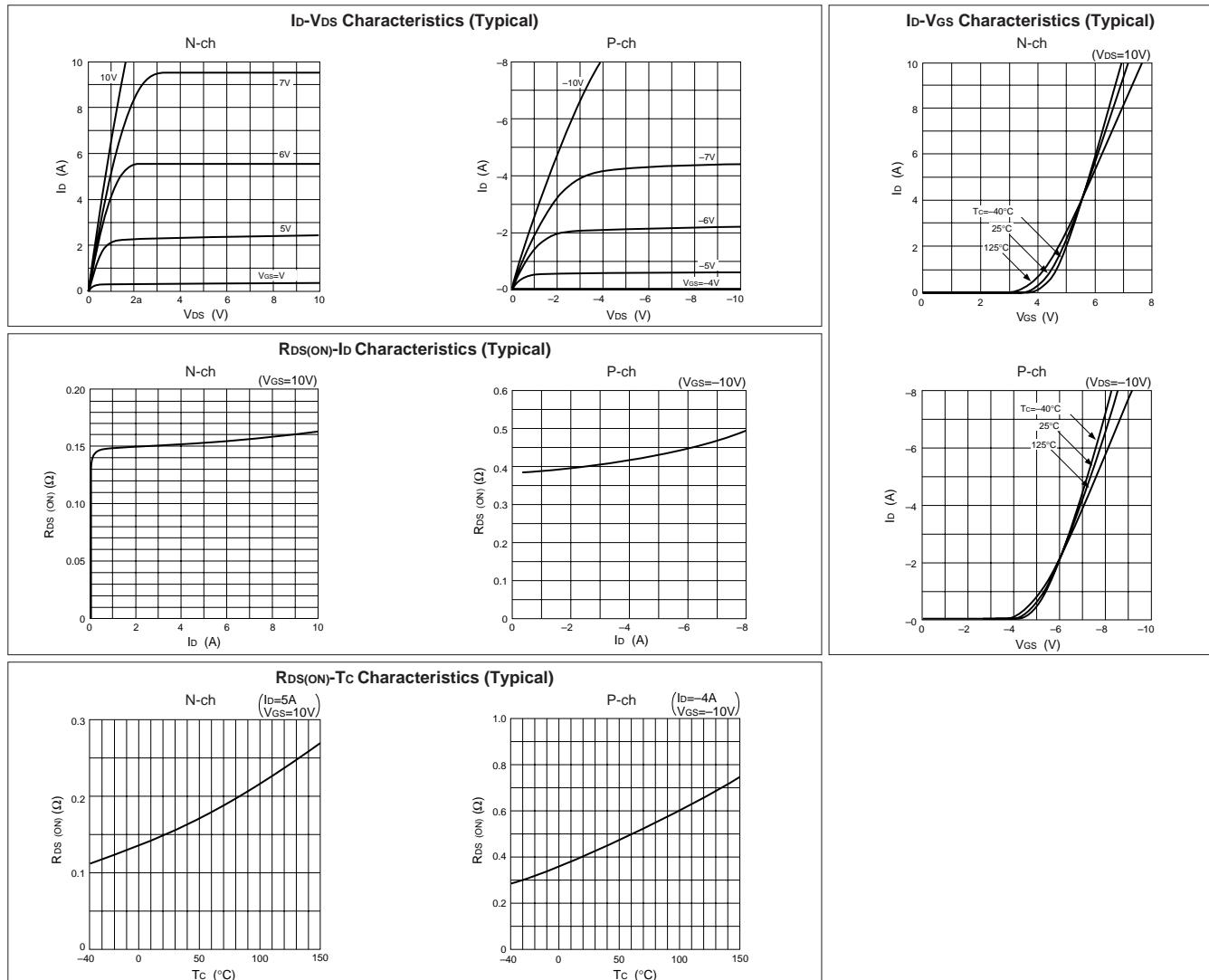


Absolute maximum ratings

(Ta=25°C)

Symbol	Ratings		Unit
	N channel	P channel	
V _{DSS}	60	-60	V
V _{GSS}	±20	±20	V
I _D	±5	±4	A
I _{D(pulse)}	±10 (PW≤1ms)	±8 (PW≤1ms)	A
E _{AS} *	2	—	mJ
P _T	5 (Ta=25°C, with all circuits operating, without heatsink) 35 (Tc=25°C, with all circuits operating, with infinite heatsink)		W
θ _{j-a}	25 (Junction-Air, Ta=25°C, with all circuits operating)		°C/W
θ _{j-c}	3.57 (Junction-Case, Tc=25°C, with all circuits operating)		°C/W
V _{iso}	1000 (Between fin and lead pin, AC)		Vrms
T _{ch}	150		°C
T _{stg}	-40 to +150		°C

 * : V_{DD}=20V, L=1mH, I_D=2A, unclamped, see Fig. E on page 15.

■ Equivalent circuit diagram

Characteristic curves


Electrical characteristics

(Ta=25°C)

Symbol	N channel						P channel					
	Specification			Unit	Conditions	Specification			Unit	Conditions		
	min	typ	max			min	typ	max				
V(BR)DSS	60			V	Id=250μA, Vgs=0V	-60			V	Id=-250μA, Vgs=0V		
IGSS			±500	nA	Vgs=±20V				±500	nA	Vgs=±20V	
IDSS			250	μA	Vds=60V, Vgs=0V				-250	μA	Vds=-60V, Vgs=0V	
VTH	2.0		4.0	V	Vds=10V, Id=250μA	-2.0			-4.0	V	Vds=-10V, Id=-250μA	
Re(yfs)	2.2	3.3		S	Vds=10V, Id=5A	1.6	2.2		S	Vds=-10V, Id=-4A		
RDS(ON)		0.17	0.22	Ω	Vgs=10V, Id=5A		0.38	0.55	Ω	Vgs=-10V, Id=-4A		
Ciss		300		pF	Vds=25V, f=1.0MHz, Vgs=0V		270		pF	Vds=-25V, f=1.0MHz, Vgs=0V		
Coss		160		pF			170		pF			
t _{on}		35		ns	Id=5A, Vdd=30V, Vgs=-10V, see Fig. 3 on page 16.		60		ns	Id=-4A, Vdd=-30V, Vgs=-10V, see Fig. 4 on page 16.		
t _{off}		35		ns			60		ns			
VSD		1.1	1.5	V	Isd=5A, Vgs=0V		-4.4	-5.5	V	Isd=-4A, Vgs=0V		
t _{rr}		140		ns	Isd=±100mA		150		ns	Isd=±100mA		

Characteristic curves

